Zener diodes primarily serve as voltage regulators to minimize voltage changes with possible operating current changes when placed in parallel across a load to be regulated. Selected Zener voltage (V_Z) nominals in numerous data sheets are available from as low as 1.6 V up to 200 V or higher with voltage tolerances of ±5% or less at a specified test current (I_ZT) when operated at 25 °C. At other I_Z operating currents, slight changes will be observed in Zener voltage from regulator impedance (Z_Z) effects or what has also been identified as dynamic impedance. The maximum Z_Z is provided in Zener data sheets at their specified test current (I_ZT) to help calculate small voltage changes (ΔV_Z) from the initial V_Z at I_ZT when operating current is changed by some small value (ΔI_Z). This simply involves Ohm's Law whereby:

ΔV_Z = ΔI_Z × Z_ZT

These considerations are important to understand good voltage regulation or when using lower voltage Zeners below 5 V where Z_ZT is comparatively high.

For I_Z values that significantly deviate from I_ZT, this calculation becomes less accurate for determining ΔV_Z since Z_Z changes with current. In those applications, the following is further provided since Z_Z typically decreases with increasing Zener current on a log-log scale as shown in Figure 1.

For Zeners operating in the linear declining slope region of the log-log plot in Figure 1, it may be demonstrated that:

Z_Z = Z_ZT × I_ZT/I_Z

As a result, a good approximation for the greater changes in Zener voltage (ΔV_Z) when current is changed from I_ZT to another value I_Z is as follows:

ΔV_Z = 2(I_ZT × Z_ZT)(I_Z - I_ZT)/(I_Z + I_ZT)
In this calculation, ΔV_Z is in volts, I_Z and I_{ZT} are in Amps, and Z_{ZT} is in Ohms.

This is applicable only for operating currents in the linear operating regions of Figure 1 where “dynamic impedance” values of the Zener p-n junction are still above the illustrated minimal parasitic region and also well within maximum rated continuous operating currents. During brief high-surge currents that are also within the rating of the device, Zeners or TVSs in avalanche breakdown may be driven into this “minimum parasitic resistance” region for good voltage clamping features.

Voltage changes with operating current will typically be greater for low-voltage Zeners (below 5 V) where their regulator impedance is much higher with field emission or tunneling effects compared to the “sharp knee” avalanche breakdown characteristics of higher voltage Zeners (well above 5 V). These differences are illustrated in Figure 2 where the described calculations for ΔV_Z above are still applicable with the higher specified values of Z_{ZT} in datasheets.

![Figure 2 • Typical Zener (I-V) Characteristics](image)

The above equations for V_Z voltage changes do no include additional effects from ambient temperature changes or thermal self-heating effects with applied Zener power (P = V_Z x I_Z) as well as thermal resistance junction to ambient. These added effects can further influence V_Z by the Zener voltage temperature coefficient (α_{VZ}) and thermal resistance (R_{θJA}) characteristics with Zeners and mounting features, particularly when power is significant relative to full rating or when heat sinking is marginal. Ambient temperature and power heating effects on Zener voltage regulators are further detailed in MicroNotes 203 and 204. Zero Temperature Coefficient or “Zero-TC” reference diodes are also described in MicroNote 205. MicroNote 070 is also now available on “Thermal Management For Discrete Semiconductors” for overall added reference.

For additional technical information, contact Design Support at: http://www.microsemi.com/designsupport or Kent Walters (kent.walters@microchip.com at 480-302-1144.
Microsemi’s product warranty is set forth in Microsemi’s Sales Order Terms and Conditions. Information contained in this publication is provided for the sole purpose of designing with and using Microsemi products. Information regarding device applications and the like is provided only for your convenience and may be superseded by updates. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is your responsibility to ensure that your application meets with your specifications. THIS INFORMATION IS PROVIDED “AS IS.” MICROSEMI MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, NON-INFRINGEMENT, MERCHANTABILITY OR FITNESS FOR A PARTICULAR PURPOSE. IN NO EVENT WILL MICROSEMI BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL OR CONSEQUENTIAL LOSS, DAMAGE, COST OR EXPENSE WHATSOEVER RELATED TO THIS INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROSEMI HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROSEMI’S TOTAL LIABILITY ON ALL CLAIMS IN RELATION TO THIS INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, YOU PAID DIRECTLY TO MICROSEMI FOR THIS INFORMATION. Use of Microsemi devices in life support, mission-critical equipment or applications, and/or safety applications is entirely at the buyer’s risk, and the buyer agrees to defend and indemnify Microsemi from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microsemi intellectual property rights unless otherwise stated.

Microsemi Corporation, a subsidiary of Microchip Technology Inc. (Nasdaq: MCHP), and its corporate affiliates are leading providers of smart, connected and secure embedded control solutions. Their easy-to-use development tools and comprehensive product portfolio enable customers to create optimal designs which reduce risk while lowering total system cost and time to market. These solutions serve more than 120,000 customers across the industrial, automotive, consumer, aerospace and defense, communications and computing markets. Headquartered in Chandler, Arizona, the company offers outstanding technical support along with dependable delivery and quality. Learn more at www.microsemi.com.